



SRC1206EF

NPN Silicon Transistor

Descriptions

- Switching application
- Interface circuit and driver circuit application

Features

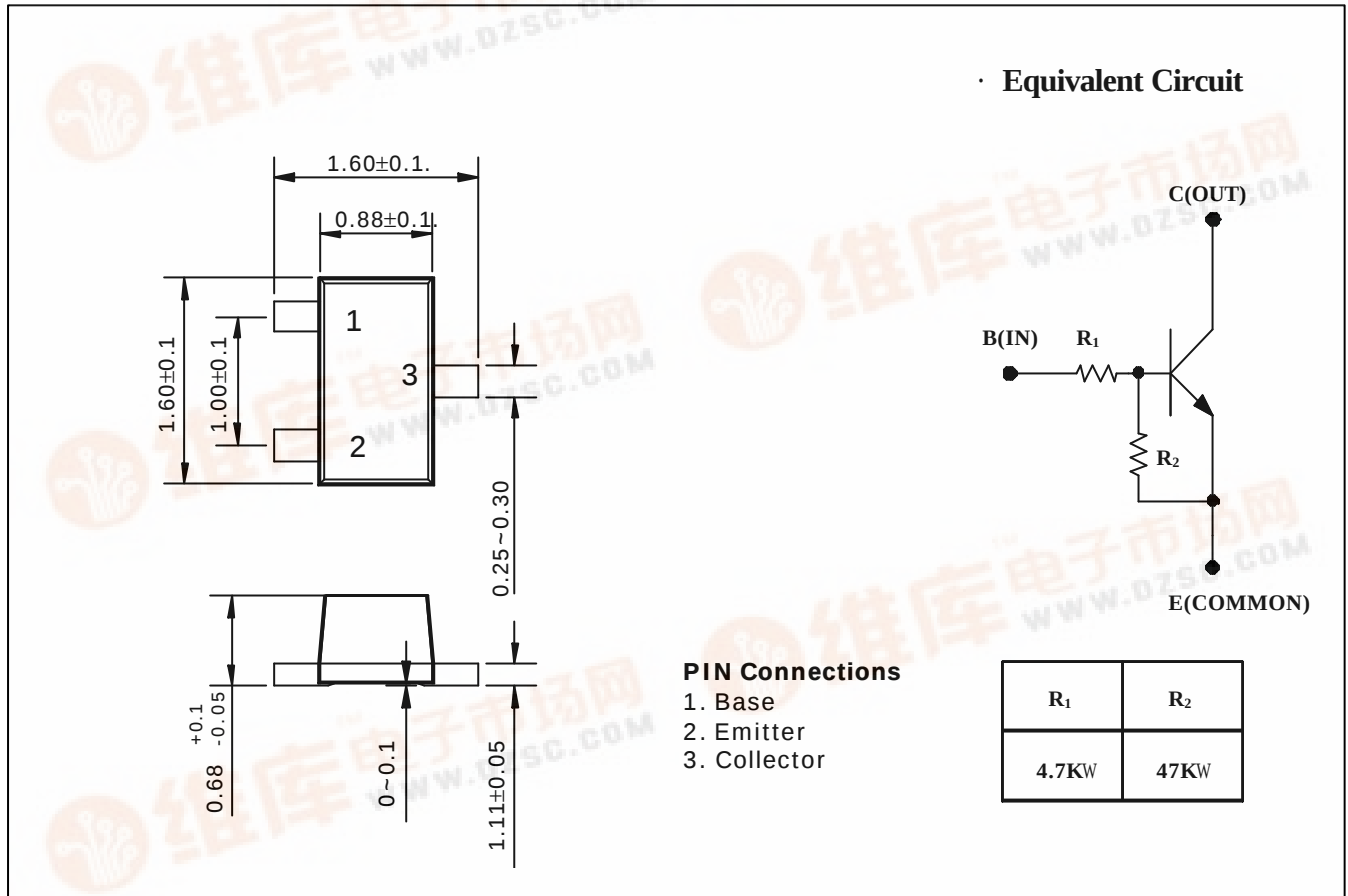
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- High packing density

Ordering Information

Type NO.	Marking	Package Code
SRC1206EF	R6	SOT - 523F

Outline Dimensions

unit : mm



Absolute maximum ratings

(Ta=25° C)

Characteristic	Symbol	Ratings	Unit
Out Voltage	V_O	50	V
Input Voltage	V_I	20	V
Out Current	I_O	100	mA
Power Dissipation	P_D	150	mW
Junction Temperature	T_J	150	°C
Storage Temperature	T_{STG}	-55 ~ 150	°C

Electrical Characteristics

(Ta=25° C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Output Cut-off Current	$I_{O(OFF)}$	$V_O=50V, V_I=0$	-	-	500	nA
DC Current Gain	G_I	$V_O=5V, I_O=10mA$	80	200	-	-
Output Voltage	$V_{O(ON)}$	$I_O=10mA, I_I=0.5mA$	-	0.1	0.3	V
Input Voltage (ON)	$V_{I(ON)}$	$V_O=0.2V, I_O=5mA$	-	0.9	1.3	V
Input Voltage (OFF)	$V_{I(OFF)}$	$V_O=5V, I_O=0.1mA$	0.5	0.65	-	V
Transition Frequency	f_T^*	$V_O=10V, I_O=5mA$	-	200	-	MHz
Input Current	I_I	$V_I=5V$	-	-	1.8	mA

* : Characteristic of Transistor Only

Electrical Characteristic Curves

Fig. 1 $I_O - V_{I(ON)}$

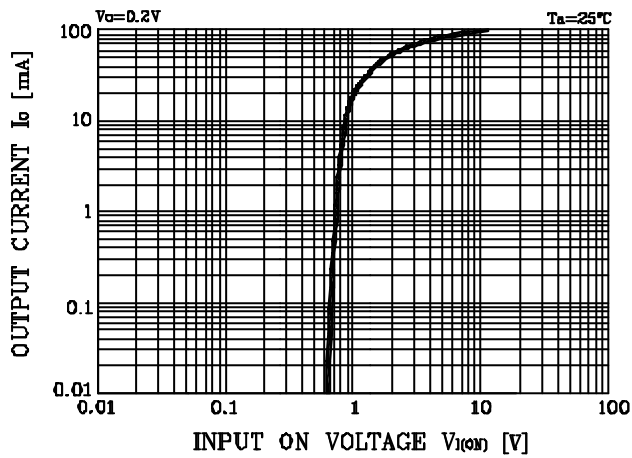


Fig. 2 $I_O - V_{I(OFF)}$

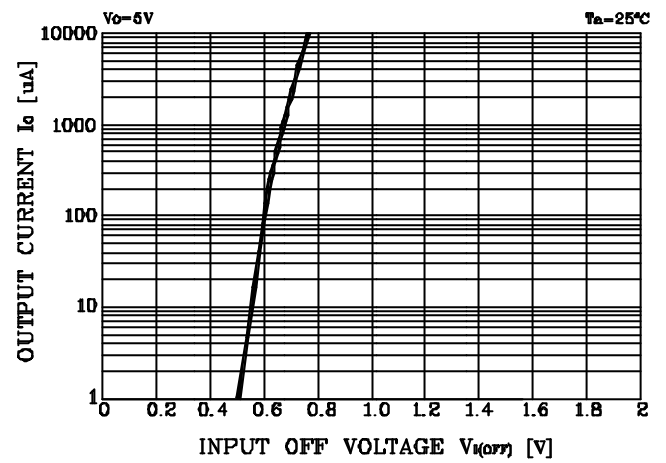


Fig. 3 $G_I - I_O$

